7.6mm x 7.6mm SUPER FLUX LED LAMP

PRELIMINARY SPEC

Part Number: WP76761CSYC/J SUPER BRIGHT YELLOW

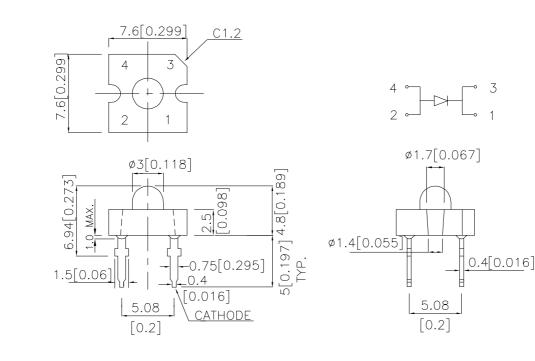
Features

- •SUPER FLUX OUTPUT.
- •DESIGN FOR HIGH CURRENT OPERATION.
- •OUTSTANDING MATERIAL EFFICIENCY.
- •RELIABLE AND RUGGED.
- •RoHS COMPLIANT.

Description

The Super Bright device is based on a light emitting diode chip made from AlGaInP and bonded on silicon substrate.

Package Dimensions



Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.25(0.01") unless otherwise noted.
- 3. Lead spacing is measured where the leads emerge from the package.

4. Specifications are subject to change without notice.

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Selection Guide								
Part No.	Dice	Lens Type	lv (mcd) [2] @ 20mA *70mA		Viewing Angle [1]			
			Min.	Тур.	2 0 1/2			
	WP76761CSYC/J SUPER BRIGHT YELLOW (AlGaInP) WATER CLEAR		2200	4500	20°			
WP76761CSYC/J		WATER GLEAR	*7500	*16000				

Notes:

1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.
2. * Luminous intensity with asterisk is measured at 70mA under 40ms pulse width; Luminous intensity / luminous flux: +/-15%.
3.Drive current between 10mA and 30mA are recommended for long term performance.
4.Operation at current below 10mA is not recommended.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Yellow	590		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Yellow	589		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Yellow	20		nm	IF=20mA
С	Capacitance	Super Bright Yellow	45		pF	VF=0V;f=1MHz
Vf [2]	Forward Voltage	Super Bright Yellow	2.3	2.8	V	IF=20mA
lr	Reverse Current	Super Bright Yellow		10	uA	$V_R = 5V$

Notes:

1. Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.

Absolute Maximum Ratings at TA=25°C

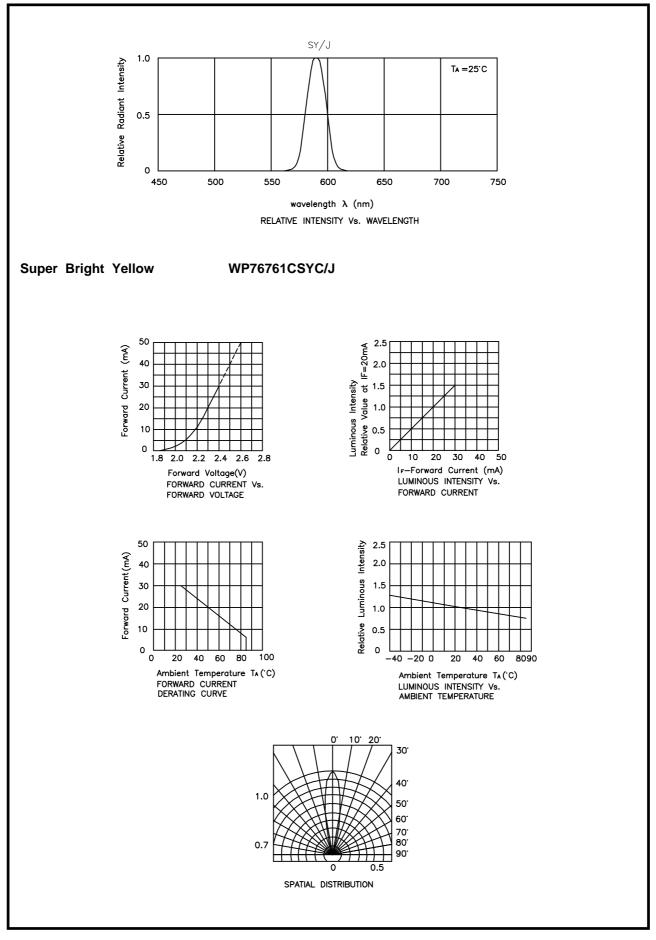
Parameter	Super Bright Yellow	Units		
Power dissipation	84	mW		
DC Forward Current	30	mA		
Peak Forward Current [1]	140	mA		
Reverse Voltage	5	V		
Operating / Storage Temperature	-40°C To +85°C			
Lead Solder Temperature [2]	260°C For 3 Seconds			
_ead Solder Temperature [3] 260°C For 5 Seconds				

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.

3. 5mm below package base.



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